Very Low Quiescent Current, 150 mA, LDO Regulator

Data Sheet

ADP165/ADP166

FEATURES

Very low quiescent current
- **I_Q = 590 nA with 0 µA load**
- **I_Q = 890 nA with 1 µA load**

Maintains very low quiescent current in dropout (pass through mode)
- **I_{Q_DROP} = 720 nA with 0 µA load**
- **I_{Q_DROP} = 1200 nA with 1 µA load**

Stable with 1 µF ± 30% ceramic input and output capacitors
Maximum operating load current (I_{LOAD_MAX}): 150 mA
Input voltage range: 2.2 V to 5.5 V
Low shutdown current: 50 nA typical
Low dropout voltage: 120 mV at 150 mA load
Initial output voltage accuracy: ±1%
Accuracy over line, load, and temperature: ±3.5%
7 fixed output voltage options: 1.2 V to 3.3 V
Adjustable output option can be set from 1.0 V to 4.2 V
PSRR: 72 dB at 100 Hz, V_{OUT} = 1.2 V
Current-limit and thermal overload protection
Logic control enable
Integrated output discharge resistor
Three package options
- **5-lead TSOT package**
- **6-lead, 2 mm × 2 mm LFCSP**
- **4-ball, 0.5 mm pitch WLCSP**

APPLICATIONS

Portable and battery-powered equipment
Post dc-to-dc regulation
Portable medical devices
Wireless sensor network (WSN) devices

TYPICAL APPLICATION CIRCUITS

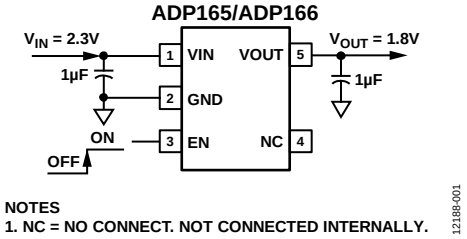


Figure 1. 5-Lead TSOT ADP165/ADP166 with Fixed Output Voltage, 1.8 V

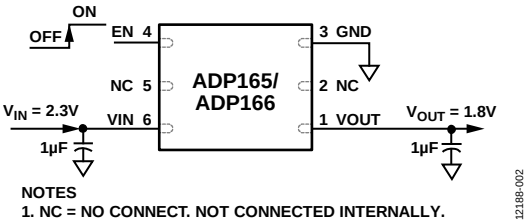


Figure 2. 6-Lead, 2 mm × 2 mm LFCSP ADP165/ADP166 with Fixed Output Voltage, 1.8 V

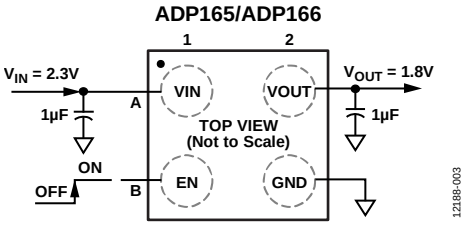


Figure 3. 4-Ball WLCSP ADP165/ADP166 with Fixed Output Voltage, 1.8 V

GENERAL DESCRIPTION

The ADP165/ADP166 are very low quiescent current, low dropout (LDO), linear regulators that operate from 2.2 V to 5.5 V and provide up to 150 mA of output current. The low 120 mV dropout voltage at a 150 mA load improves efficiency and allows operation over a wide input voltage range.

The ADP165/ADP166 are specifically designed for stable operation with a tiny 1 µF ± 30% ceramic input and output capacitors to meet the requirements of high performance, space constrained applications.

The ADP165/ADP166 are available in seven fixed output voltage options, ranging from 1.2 V to 3.3 V, and an adjustable output option. The ADP165 also includes a switched resistor to discharge the output automatically when the LDO is disabled. The ADP166 is identical to the ADP165, but it does not include the output discharge function.

Short-circuit and thermal overload protection circuits prevent damage in adverse conditions. The ADP165/ADP166 are available in a tiny 5-lead TSOT, a 6-lead LFCSP, and a 4-ball, 0.5 mm pitch WLCSP package for the smallest footprint solution to meet a variety of portable power applications.

Rev. C
Document Feedback
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A.
Tel: 781.329.4700
©2026 Analog Devices, Inc. All rights reserved.
Technical Support
www.analog.com

Downloaded from Arrow.com.

TABLE OF CONTENTS

Features ... 1
Applications ... 1
Typical Application Circuits ... 1
General Description ... 1
Revision History ... 2
Specifications ... 3
Recommended Specifications: Input and Output Capacitors 4
Absolute Maximum Ratings ... 5
Thermal Data ... 5
Thermal Resistance ... 5
ESD Caution ... 5
Pin ConfigurationS and Function Descriptions ... 6
Typical Performance Characteristics ... 9
Theory of Operation ... 13
Applications Information ... 15
Capacitor Selection ... 15
Enable Feature ... 16
Undervoltage Lockout (UVLO) ... 16
Current-Limit and Thermal Overload Protection ... 16
Thermal Considerations ... 17
PCB Layout Considerations ... 20
Light Sensitivity of WLCSPs ... 21
Outline Dimensions ... 22
Ordering Guide ... 23

REVISION HISTORY

7/26—Rev. B to Rev. C

Updated Outline Dimensions ... 22
Changes to Ordering Guide ... 23

1/25—Rev. A to Rev. B

Changes to Absolute Maximum Ratings ... 5

11/14—Rev. 0 to Rev. A

Change to Features Section ... 1
Change to Theory of Operation Section ... 13

9/14—Revision 0: Initial Version

Downloaded from Arrow.com.

SPECIFICATIONS

V_{IN} = (V_{OUT} + 0.5 V) or 2.2 V, whichever is greater, EN = V_{IN}, I_{OUT} = 10 mA, C_{IN} = C_{OUT} = 1 µF, T_A = 25°C, T_J = −40°C to +125°C for minimum/maximum specifications, unless otherwise noted.

Table 1.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
INPUT VOLTAGE RANGE	V_{IN}	T_J = −40°C to +125°C	2.2		5.5	V
OPERATING SUPPLY CURRENT	I_Q	I_{OUT} = 0 µA, T_A = 25°C		590	1250	nA
		I_{OUT} = 0 µA, T_J = −40°C to +125°C			2.4	µA
		I_{OUT} = 1 µA, T_A = 25°C		890	1800	nA
		I_{OUT} = 1 µA ,T_J = −40°C to +125°C			3.0	µA
		I_{OUT} = 100 µA, T_A = 25°C		2.6	4.8	µA
		I_{OUT} = 100 µA, T_J = −40°C to +125°C			6.2	µA
		I_{OUT} = 10 mA, T_A = 25°C		11	19	µA
		I_{OUT} = 150 mA , T_A = 25°C		42	65	µA
SUPPLY CURRENT IN DROPOUT (PASS THROUGH MODE)	I_{Q_DROP}	I_{OUT} = 0 µA, V_{IN} = V_{OUT} − 0.2 V, T_A = 25°C		720	1600	nA
		I_{OUT} = 0 µA, V_{IN} = V_{OUT} − 0.2 V, T_J = −40°C to +125°C			2.7	µA
		I_{OUT} = 1 µA, V_{IN} = V_{OUT} − 0.2 V, T_A = 25°C		1200	2400	nA
		I_{OUT} = 1 µA, V_{IN} = V_{OUT} − 0.2 V, T_J = −40°C to +125°C			3.5	µA
SHUTDOWN CURRENT	$I_{GND\text{-}SD}$	EN = GND		50		nA
		EN = GND, T_J = −40°C to +125°C			1	µA
FIXED OUTPUT VOLTAGE ACCURACY	$V_{OUT_ACCURACY}$	I_{OUT} = 10 mA, T_A = 25°C	−1		+1	%
		0 µA < I_{OUT} < 150 mA, V_{IN} = (V_{OUT} + 0.5 V) to 5.5 V, T_A = 25°C	−2		+2	%
		0 µA < I_{OUT} < 150 mA, V_{IN} = (V_{OUT} + 0.5 V) to 5.5 V, T_J = −40°C to +125°C	−3.5		+3.5	%
ADJ PIN VOLTAGE ACCURACY[1]	V_{ADJ}	I_{OUT} = 10 mA	0.99	1.0	1.01	V
		0 µA < I_{OUT} < 150 mA, V_{IN} = (V_{OUT} + 0.5 V) to 5.5 V	0.98		1.02	V
		0 µA < I_{OUT} < 150 mA, V_{IN} = (V_{OUT} + 0.5 V) to 5.5 V, T_J = −40°C to +125°C	0.97		1.03	V
REGULATION						
Line Regulation	$\Delta V_{OUT}/\Delta V_{IN}$	V_{IN} = (V_{OUT} + 0.5 V) to 5.5 V, T_J = −40°C to +125°C	−0.1		+0.1	%/V
Load Regulation[2]	$\Delta V_{OUT}/\Delta I_{OUT}$	I_{OUT} = 100 µA to 150 mA		0.004	0.01	%/mA
DROPOUT VOLTAGE[3]	$V_{DROPOUT}$	V_{OUT} = 3.3 V				
		I_{OUT} = 10 mA		45	110	mV
		I_{OUT} = 150 mA		120	225	mV
ADJ PIN INPUT BIAS CURRENT	$ADJ_{I\text{-}BIAS}$	2.2 V ≤ V_{IN} ≤ 5.5 V, ADJ connected to VOUT		10		nA
ACTIVE PULL-DOWN RESITANCE (ADP165)	$R_{PULL\text{-}DOWN}$	V_{OUT} = 3.3 V, R_{LOAD} = ∞		300	600	Ω
START-UP TIME[4]	$T_{START\text{-}UP}$	V_{OUT} = 3.3 V		1100		µs
MAXIMUM OPERATING LOAD CURRENT	I_{LOAD_MAX}			150		mA
CURRENT-LIMIT THRESHOLD[5]	I_{LIMIT}		215	320	500	mA
THERMAL SHUTDOWN						
Thermal Shutdown Threshold	TS_{SD}	T_J rising		150		°C
Thermal Shutdown Hysteresis	$TS_{SD\text{-}HYS}$			15		°C
EN INPUT						
EN Input Logic High	V_{IH}	2.2 V ≤ V_{IN} ≤ 5.5 V	1.2			V
EN Input Logic Low	V_{IL}	2.2 V ≤ V_{IN} ≤ 5.5 V			0.4	V
EN Input Leakage Current	$V_{I\text{-}LEAKAGE}$	EN = V_{IN} or GND		0.1		µA
		EN = V_{IN} or GND, T_J = −40°C to +125°C			1	µA

Downloaded from Arrow.com.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
UNDERVOLTAGE LOCKOUT (UVLO)						
Input Voltage Rising	$UVLO_{RISE}$				2.19	V
Input Voltage Falling	$UVLO_{FALL}$		1.60			V
Hysteresis	$UVLO_{HYS}$			85		mV
OUTPUT NOISE	OUT_{NOISE}	10 Hz to 100 kHz, V_{IN} = 5 V, V_{OUT} = 3.3 V		105		µV rms
		10 Hz to 100 kHz, V_{IN} = 5 V, V_{OUT} = 2.5 V		100		µV rms
		10 Hz to 100 kHz, V_{IN} = 5 V, V_{OUT} = 1.2 V		80		µV rms
POWER SUPPLY REJECTION RATIO	PSRR	100 Hz, V_{IN} = 5 V, V_{OUT} = 3.3 V		60		dB
		100 Hz, V_{IN} = 5 V, V_{OUT} = 2.5 V		65		dB
		100 Hz, V_{IN} = 5 V, V_{OUT} = 1.2 V		72		dB
		1 kHz, V_{IN} = 5 V, V_{OUT} = 3.3 V		50		dB
		1 kHz, V_{IN} = 5 V, V_{OUT} = 2.5 V		50		dB
		1 kHz, V_{IN} = 5 V, V_{OUT} = 1.2 V		62		dB

[1] Accuracy when VOUT is connected directly to ADJ. When the VOUT voltage is set by the external feedback resistors, the absolute accuracy in adjust mode depends on the tolerances of the resistors used.
[2] Based on an endpoint calculation using 0 µA and 150 mA loads.
[3] Dropout voltage is defined as the input-to-output voltage differential when the input voltage is set to the nominal output voltage. This applies only for output voltages above 2.2 V.
[4] Start-up time is defined as the time between the rising edge of EN to VOUT being at 90% of its nominal value.
[5] Current-limit threshold is defined as the current at which the output voltage drops to 90% of the specified typical value. For example, the current limit for a 3.0 V output voltage is defined as the current that causes the output voltage to drop to 90% of 3.0 V, or 2.7 V.

RECOMMENDED SPECIFICATIONS: INPUT AND OUTPUT CAPACITORS

Table 2.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
INPUT AND OUTPUT CAPACITOR						
Minimum Input and Output Capacitance[1]	C_{IN}; C_{OUT}	C_{IN} and C_{OUT} tolerance = ±30%, T_A = −40°C to +125°C	0.7	1		µF
Capacitor Effective Series Resistance (ESR)	R_{ESR}	T_A = −40°C to +125°C	0.001		0.2	Ω

[1] The minimum input and output capacitance must be greater than 0.7 µF over the full range of operating conditions. The full range of operating conditions in the application must be considered during device selection to ensure that the minimum capacitance specification is met. X7R and X5R type capacitors are recommended; however, Y5V and Z5U capacitors are not recommended for use with any LDO.

Downloaded from Arrow.com.

ABSOLUTE MAXIMUM RATINGS

Table 3.

Parameter	Rating
VIN to GND	−0.3 V to +6.5 V
VOUT to GND	−0.3 V to VIN
EN to GND	−0.3 V to +6.5 V
ADJ to GND	−0.3 V to VIN
NC to GND	−0.3 V to VIN
Storage Temperature Range	−65°C to +150°C
Operating Junction Temperature Range	−40°C to +125°C
Operating Ambient Temperature Range	−40°C to +125°C
Soldering Conditions	JEDEC J-STD-020

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

THERMAL DATA

Absolute maximum ratings only apply individually; they do not apply in combination. The ADP165/ADP166 can be damaged when the junction temperature limits are exceeded. Monitoring ambient temperature does not guarantee that the junction temperature (T_J) is within the specified temperature limits. In applications with high power dissipation and poor thermal resistance, the maximum ambient temperature may have to be derated.

In applications with moderate power dissipation and low printed circuit board (PCB) thermal resistance, the maximum ambient temperature can exceed the maximum limit as long as the junction temperature is within specification limits. T_J is dependent on the ambient temperature (T_A), the power dissipation of the device (P_D), and the junction-to-ambient thermal resistance of the package (θ_{JA}).

Maximum T_J is calculated from T_A and P_D using the formula

$$T_J = T_A + (P_D \times \theta_{JA})$$

Junction-to-ambient thermal resistance (θ_{JA}) of the package is based on modeling and calculation using a 4-layer board. The junction-to-ambient thermal resistance is highly dependent on the application and board layout. In applications where high maximum power dissipation exists, close attention to thermal board design is required. The value of θ_{JA} may vary, depending on PCB material, layout, and environmental conditions. The specified values of θ_{JA} are based on a 4-layer, 4 inches × 3 inches, circuit board. Refer to JESD 51-7 and JESD 51-9 for detailed information on the board construction.

Ψ_{JB} is the junction to board thermal characterization parameter with units of °C/W. Ψ_{JB} of the package is based on modeling and calculation using a 4-layer board. The JESD51-12, *Guidelines for Reporting and Using Electronic Package Thermal Information*, states that thermal characterization parameters are not the same as thermal resistances. Ψ_{JB} measures the component power flowing through multiple thermal paths rather than a single path as in thermal resistance (θ_{JB}). Therefore, Ψ_{JB} thermal paths include convection from the top of the package as well as radiation from the package, factors that make Ψ_{JB} more useful in real-world applications. Maximum T_J is calculated from the board temperature (T_B) and P_D using the formula

$$T_J = T_B + (P_D \times \Psi_{JB})$$

Refer to JESD51-8 and JESD51-12 for more detailed information about Ψ_{JB}.

THERMAL RESISTANCE

θ_{JA} and Ψ_{JB} are specified for worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 4. Thermal Resistance

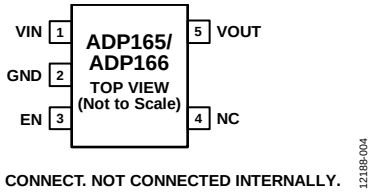
Package Type	θ_{JA}	Ψ_{JB}	Unit
5-Lead TSOT	170	43	°C/W
6-Lead LFCSP	50.2	18.2	°C/W
4-Ball, 0.4 mm Pitch WLCSP	260	58	°C/W

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

Downloaded from Arrow.com.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS



NOTES
1. NC = NO CONNECT. NOT CONNECTED INTERNALLY.

Figure 4. 5-Lead TSOT, Fixed Output Pin Configuration

Table 5. Fixed Output, 5-Lead TSOT Pin Function Descriptions

Pin No.	Mnemonic	Description
1	VIN	Regulator Input Supply. Bypass VIN to GND with a 1 µF or greater capacitor.
2	GND	Ground.
3	EN	Enable Input. Drive EN high to turn on the regulator; drive EN low to turn off the regulator. For automatic startup, connect EN to VIN.
4	NC	No Connect. This pin is not connected internally.
5	VOUT	Regulated Output Voltage. Bypass VOUT to GND with a 1 µF or greater capacitor.

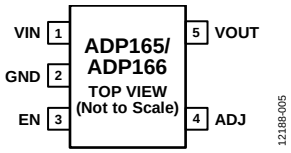
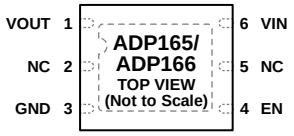


Figure 5. 5-Lead TSOT, Adjustable Output Pin Configuration

Table 6. Adjustable Output, 5-Lead TSOT Pin Function Descriptions

Pin No.	Mnemonic	Description
1	VIN	Regulator Input Supply. Bypass VIN to GND with a 1 µF or greater capacitor.
2	GND	Ground.
3	EN	Enable Input. Drive EN high to turn on the regulator; drive EN low to turn off the regulator. For automatic startup, connect EN to VIN.
4	ADJ	Output Voltage Adjust Pin. Connect the midpoint of the voltage divider between VOUT and GND to this pin to set the output voltage.
5	VOUT	Regulated Output Voltage. Bypass VOUT to GND with a 1 µF or greater capacitor.

Downloaded from Arrow.com.



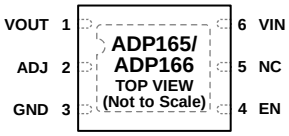
NOTES
1. NC = NO CONNECT. NOT CONNECTED INTERNALLY.
2. THE EXPOSED PAD MUST BE CONNECTED TO GROUND. THE EXPOSED PAD ENHANCES THE THERMAL PERFORMANCE OF THE PACKAGE.

12188-006

Figure 6. 6-Lead LFCSP, Fixed Output Pin Configuration

Table 7. Fixed Output, 6-Lead LFCSP Pin Function Descriptions

Pin No.	Mnemonic	Description
1	VOUT	Regulated Output Voltage. Bypass VOUT to GND with a 1 µF or greater capacitor.
2	NC	No Connect. This pin is not connected internally.
3	GND	Ground.
4	EN	Enable Input. Drive EN high to turn on the regulator; drive EN low to turn off the regulator. For automatic startup, connect EN to VIN.
5	NC	No Connect. This pin is not connected internally. Connect this pin to GND or leave open.
6	VIN	Regulator Input Supply. Bypass VIN to GND with a 1 µF or greater capacitor.
	EPAD	Exposed Pad. The exposed pad must be connected to ground. The exposed pad enhances the thermal performance of the package.



NOTES
1. NC = NO CONNECT. NOT CONNECTED INTERNALLY.
2. THE EXPOSED PAD MUST BE CONNECTED TO GROUND. THE EXPOSED PAD ENHANCES THE THERMAL PERFORMANCE OF THE PACKAGE.

12188-007

Figure 7. 6-Lead LFCSP, Adjustable Output Pin Configuration

Table 8. Adjustable Output, 6-Lead LFCSP Pin Function Descriptions

Pin No.	Mnemonic	Description
1	VOUT	Regulated Output Voltage. Bypass VOUT to GND with a 1 µF or greater capacitor.
2	ADJ	Output Voltage Adjust Pin. Connect the midpoint of the voltage divider between VOUT and GND to this pin to set the output voltage.
3	GND	Ground.
4	EN	Enable Input. Drive EN high to turn on the regulator; drive EN low to turn off the regulator. For automatic startup, connect EN to VIN.
5	NC	No Connect. This pin is not connected internally.
6	VIN	Regulator Input Supply. Bypass VIN to GND with a 1 µF or greater capacitor.
	EPAD	Exposed Pad. The exposed pad must be connected to ground. The exposed pad enhances the thermal performance of the package.

Downloaded from Arrow.com.

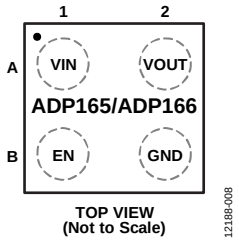


Figure 8. 4-Ball WLCSP Pin Configuration

Table 9. 4-Ball WLCSP Pin Function Descriptions

Pin No.	Mnemonic	Description
A1	VIN	Regulator Input Supply. Bypass VIN to GND with a 1 µF or greater capacitor.
B1	EN	Enable Input. Drive EN high to turn on the regulator; drive EN low to turn off the regulator. For automatic startup, connect EN to VIN.
A2	VOUT	Regulated Output Voltage. Bypass VOUT to GND with a 1 µF or greater capacitor.
B2	GND	Ground.

Downloaded from Arrow.com.

TYPICAL PERFORMANCE CHARACTERISTICS

V_{IN} = 3.8 V, V_{OUT} = 3.3 V, I_{OUT} = 1 mA, C_{IN} = C_{OUT} = 1 µF, T_A = 25°C, unless otherwise noted.

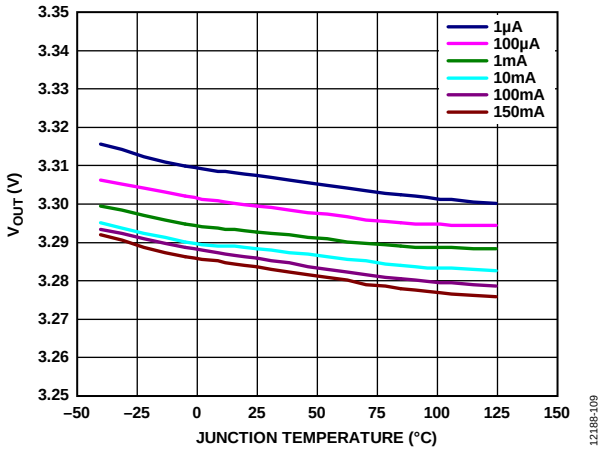


Figure 9. Output Voltage (V_{OUT}) vs. Junction Temperature

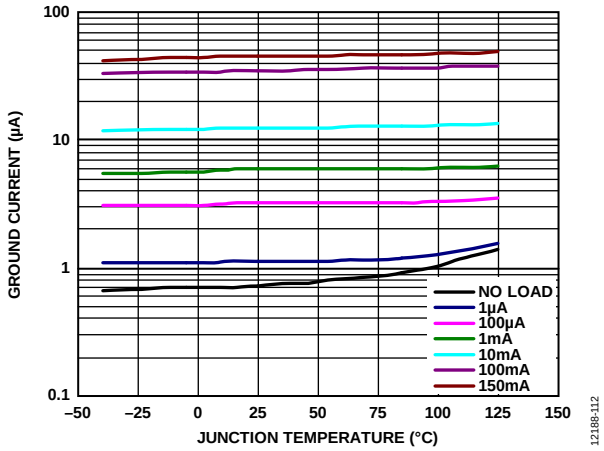


Figure 12. Ground Current vs. Junction Temperature

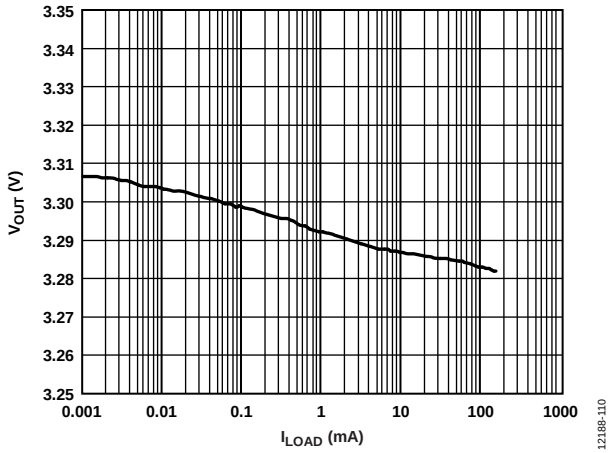


Figure 10. Output Voltage (V_{OUT}) vs. Load Current (I_{LOAD})

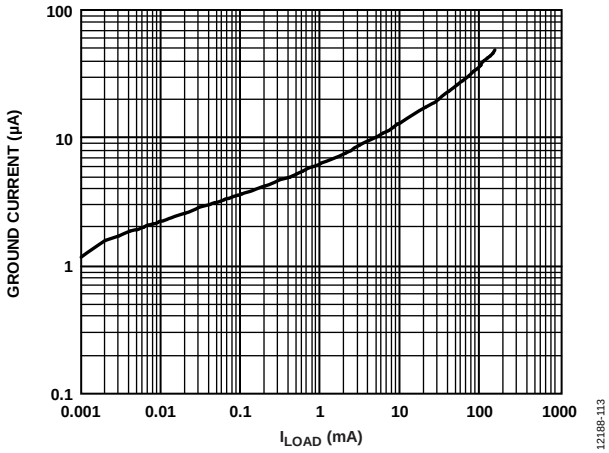


Figure 13. Ground Current vs. Load Current (I_{LOAD})

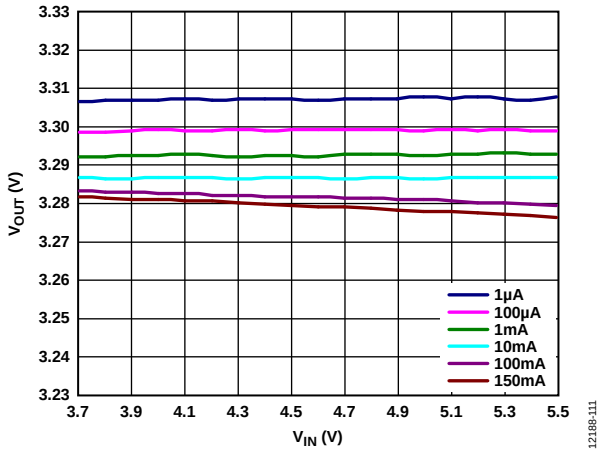


Figure 11. Output Voltage (V_{OUT}) vs. Input Voltage (V_{IN})

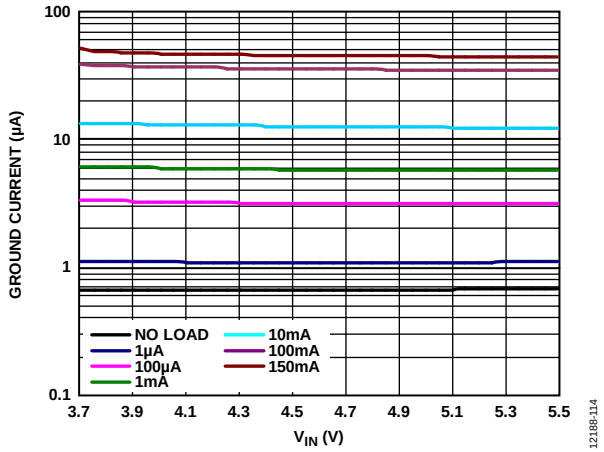


Figure 14. Ground Current vs. Input Voltage (V_{IN})

Downloaded from Arrow.com.

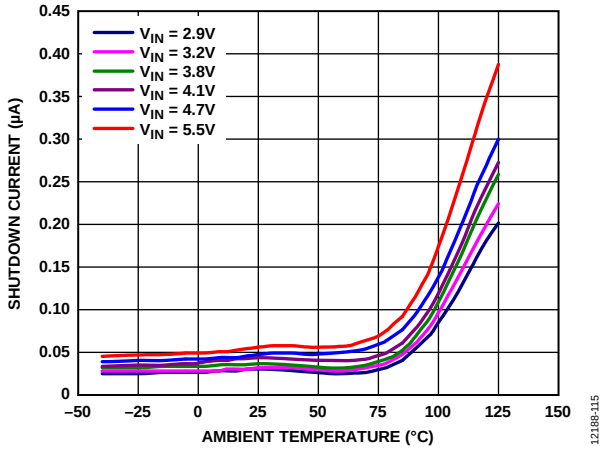


Figure 15. Shutdown Current vs. Ambient Temperature at Various Input Voltages

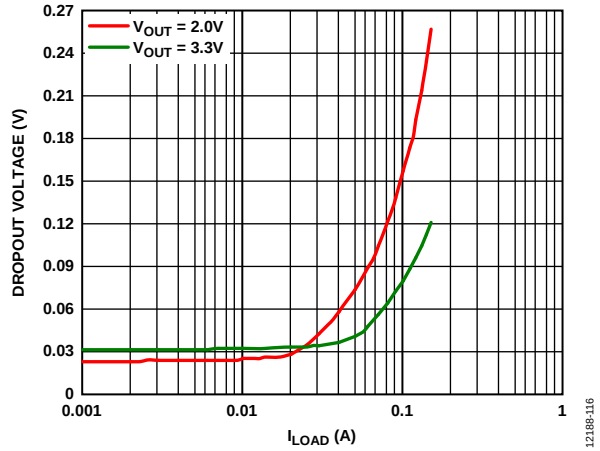


Figure 16. Dropout Voltage vs. Load Current (I_{LOAD})

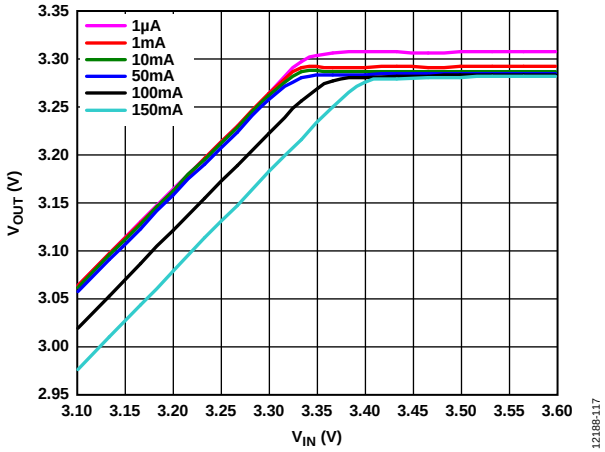


Figure 17. Output Voltage (V_{OUT}) vs. Input Voltage (V_{IN}) in Dropout

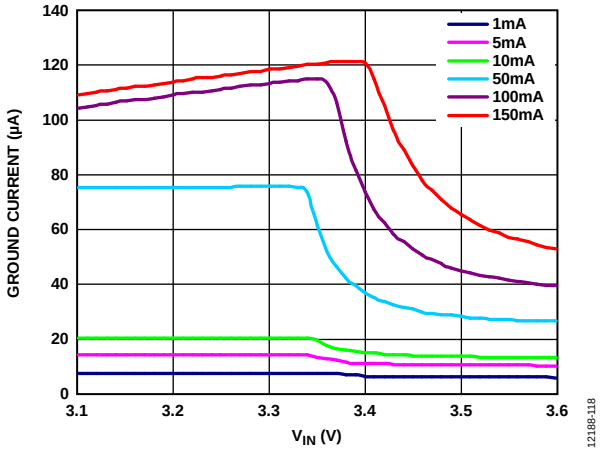


Figure 18. Ground Current vs. Input Voltage (V_{IN}) in Dropout

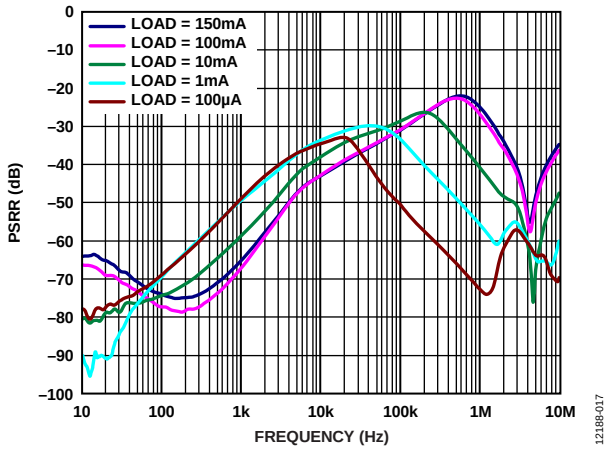


Figure 19. Power Supply Rejection Ratio (PSRR) vs. Frequency, Various Load Currents, V_{OUT} = 1.2 V, V_{IN} = 2.2 V

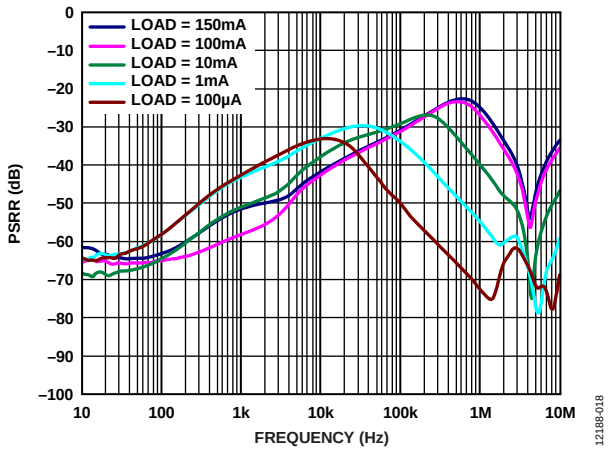


Figure 20. PSRR vs. Frequency, Various Load Currents , V_{OUT} = 2.5 V, V_{IN} = 3.5 V

Downloaded from Arrow.com.

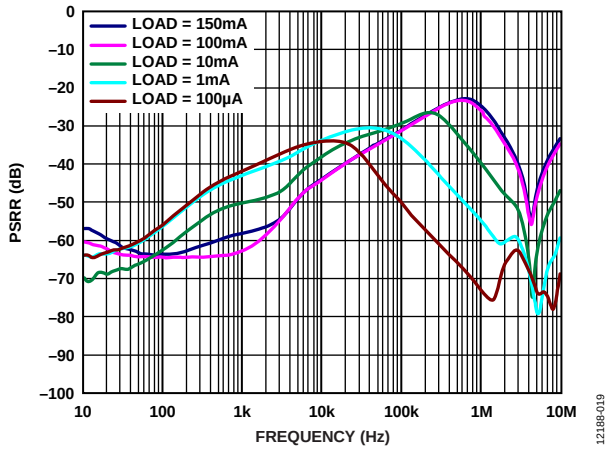


Figure 21. PSRR vs. Frequency, Various Load Currents, V_{OUT} = 3.3 V, V_{IN} = 4.3 V

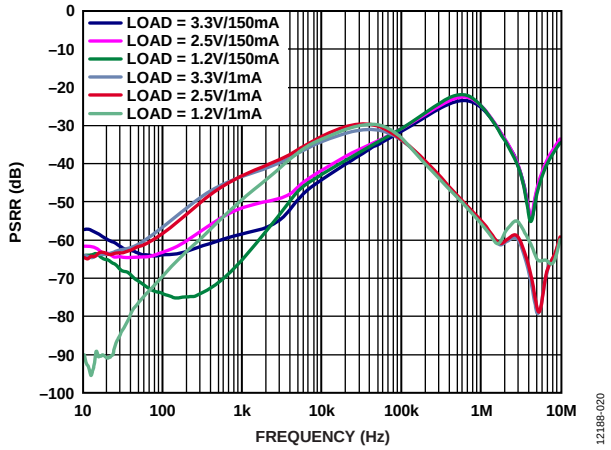


Figure 22. PSRR vs. Frequency, Various Load Currents, $V_{IN} - V_{OUT}$ = 1 V

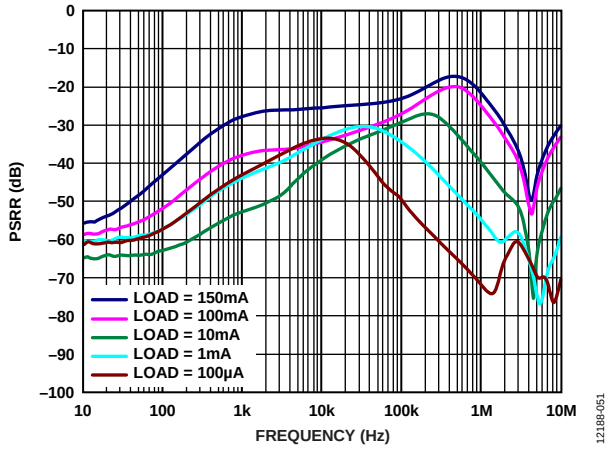


Figure 23. PSRR vs. Frequency, Various Load Currents, V_{OUT} = 2.5 V, V_{IN} = 3.0 V

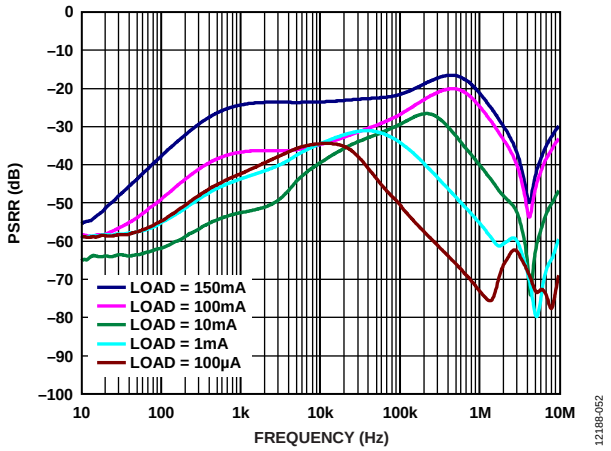


Figure 24. PSRR vs. Frequency, Various Load Currents, V_{OUT} = 3.3 V, V_{IN} = 3.8 V

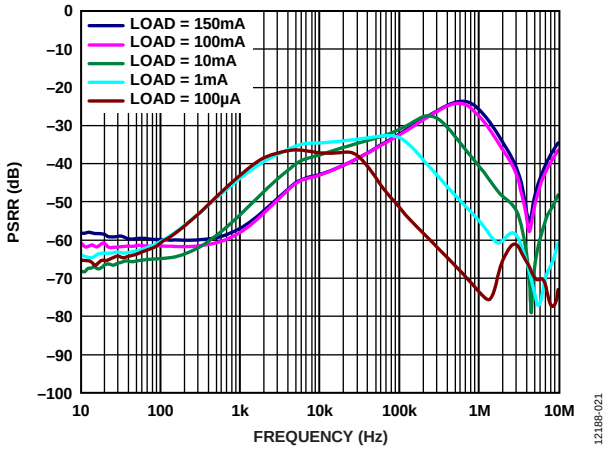


Figure 25. Adjustable ADP165/ADP166 PSRR vs. Frequency, Various Load Currents, V_{OUT} = 3.3 V, V_{IN} = 4.3 V

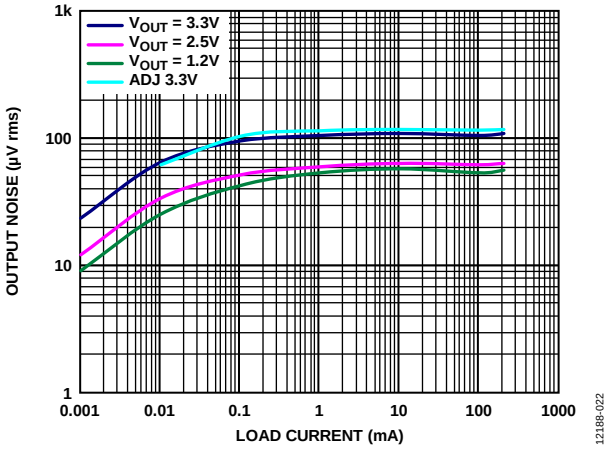


Figure 26. Output Noise vs. Load Current and Output Voltage, V_{IN} = 5 V, C_{OUT} = 1 µF

Downloaded from Arrow.com.

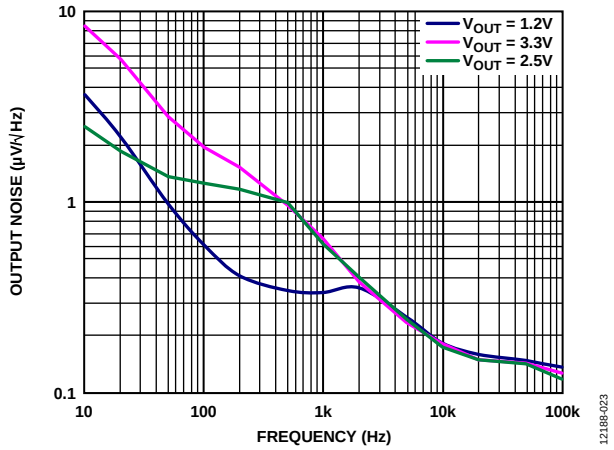


Figure 27. Output Noise Spectral Density, V_{IN} = 5 V, I_{LOAD} = 10 mA, C_{OUT} = 1 µF

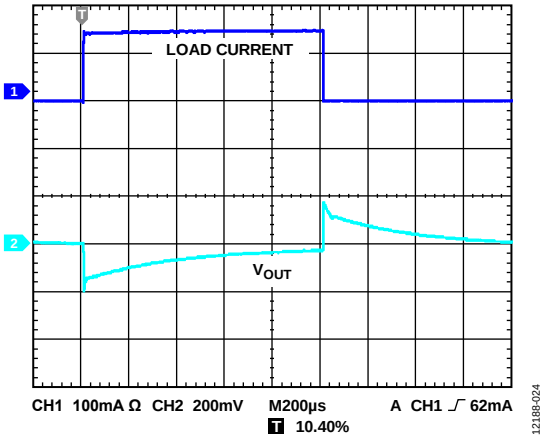


Figure 28. Load Transient Response, C_{IN} = C_{OUT} = 1 µF, I_{LOAD} = 1 mA to 150 mA, 200 ns Rise Time, CH1 = Load Current, CH2 = V_{OUT}

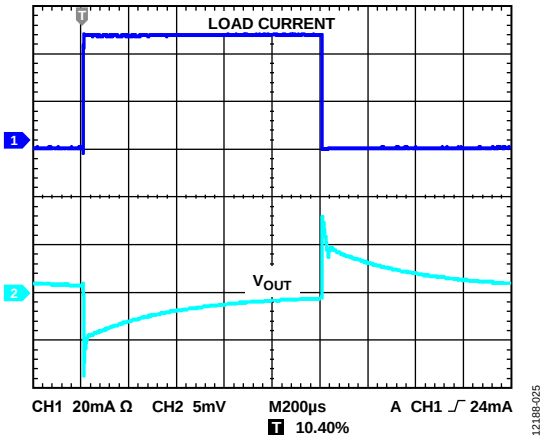


Figure 29. Load Transient Response, C_{IN} = C_{OUT} = 1 µF, I_{LOAD} = 1 mA to 50 mA, 200 ns Rise Time, CH1 = Load Current, CH2 = V_{OUT}

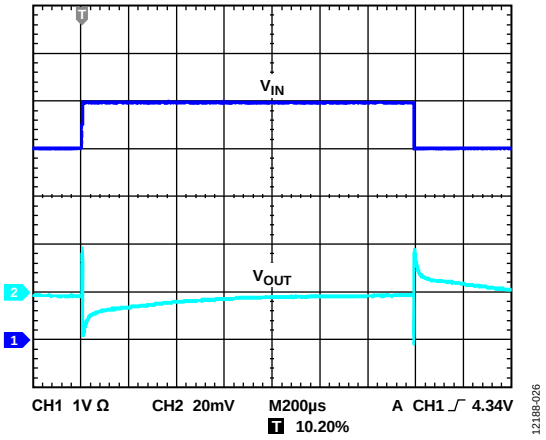


Figure 30. Line Transient Response, V_{IN} = 4 V to 5 V, C_{IN} = C_{OUT} = 1 µF, I_{LOAD} = 150 mA, CH1 = V_{IN}, CH2 = V_{OUT}

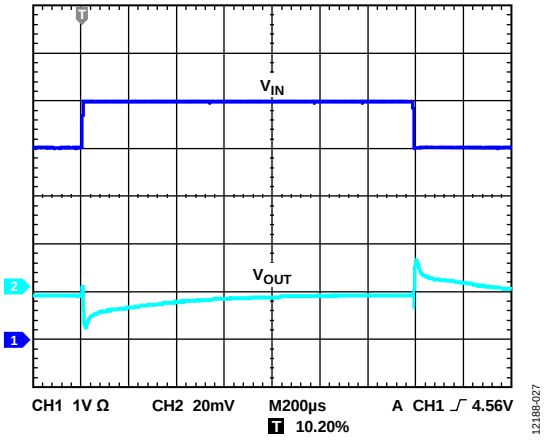


Figure 31. Line Transient Response, V_{IN} = 4 V to 5 V, C_{IN} = 1 µF, C_{OUT} = 10 µF, I_{LOAD} = 150 mA, CH1 = V_{IN}, CH2 = V_{OUT}

Downloaded from Arrow.com.

THEORY OF OPERATION

The ADP165/ADP166 are very low quiescent current, low dropout linear regulators that operate from 2.2 V to 5.5 V and can provide up to 150 mA of output current. Drawing only 590 nA (typical) at no load and a low 42 µA of quiescent current (typical) at full load makes the ADP165/ADP166 ideal for battery-operated portable equipment. Shutdown current consumption is typically 50 nA.

Using new innovative design techniques, the ADP165/ADP166 provide very low quiescent current and superior transient performance for digital and RF applications. The ADP165/ADP166 are also optimized for use with small 1 µF ceramic capacitors.

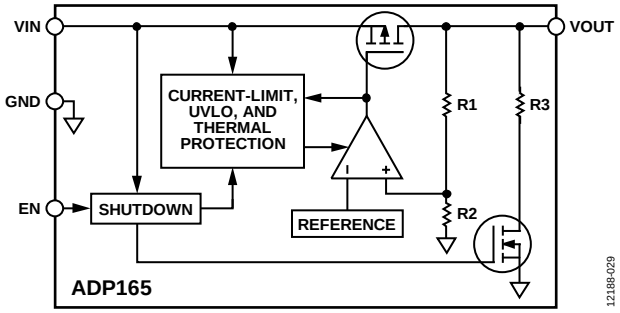


Figure 32. Internal Block Diagram, Fixed Output with Output Discharge Function

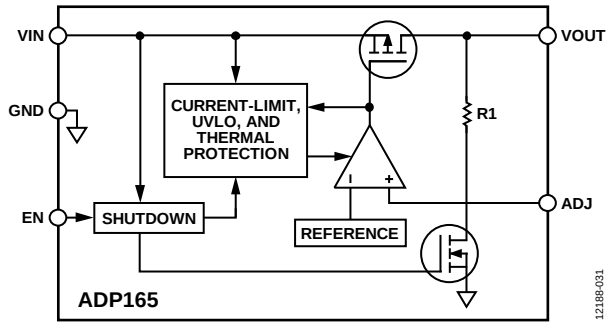


Figure 33. Internal Block Diagram, Adjustable Output with Output Discharge Function

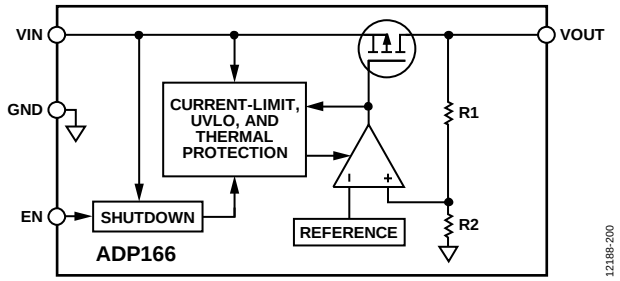


Figure 34. Internal Block Diagram, Fixed Output Without Output Discharge Function

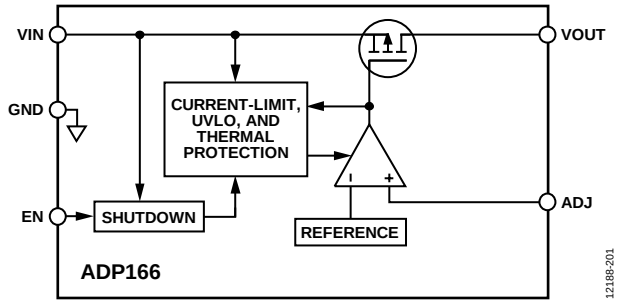


Figure 35. Internal Block Diagram, Adjustable Output Without Output Discharge Function

Internally, the ADP165/ADP166 consist of a reference, an error amplifier, a feedback voltage divider, and a PMOS pass transistor. Output current is delivered via the PMOS pass device, which is controlled by the error amplifier. The error amplifier compares the reference voltage with the feedback voltage from the output and amplifies the difference. If the feedback voltage is lower than the reference voltage, the gate of the PMOS device is pulled lower, allowing more current to pass and increasing the output voltage. If the feedback voltage is higher than the reference voltage, the gate of the PMOS device is pulled higher, allowing less current to pass and decreasing the output voltage.

The adjustable ADP165/ADP166 have an output voltage range of 1.0 V to 4.2 V. The output voltage is set by the ratio of two external resistors, which are the same as the R1 and R2 resistors in Figure 32 and Figure 34, but are connected through the ADJ pin. The device servos the output to maintain the voltage at the ADJ pin at 1.0 V referenced to ground. The current in R1 is then equal to 1.0 V/R2, and the current in R1 is the current in R2 plus the ADJ pin bias current. The ADJ pin bias current, 10 nA at 25°C, flows through R1 into the ADJ pin.

Calculate the output voltage using the following equation:

$$V_{OUT} = 1.0\ \text{V}(1 + R1/R2) + (ADJ_{I\text{-}BIAS})(R1)$$

The value of R1 must be less than 200 kΩ to minimize errors in the output voltage caused by the ADJ pin bias current. For example, when R1 and R2 each equal 200 kΩ, the output voltage is 2.0 V. The output voltage error introduced by the ADJ pin bias current is 2 mV or 0.05%, assuming a typical ADJ pin bias current of 10 nA at 25°C.

Downloaded from Arrow.com.

To minimize quiescent current in the ADP165/ADP166, Analog Devices, Inc., recommends using high values of resistance for R1 and R2. Using a value of 1 MΩ for R2 keeps the total, no load quiescent current below 2 μA. However, note that a high value of resistance introduces a small output voltage error. For example, assuming R1 and R2 are 1 MΩ, the output voltage is 2 V. Taking into account the nominal ADJ pin bias current of 10 nA, the output voltage error is 0.25%.

Note that, in shutdown, the output is turned off, and the divider current is zero.

The ADP165 also includes an output discharge resistor to force the output voltage to zero when the LDO is disabled. This ensures that the output of the LDO is always in a well-defined state, whether it is enabled or not. The ADP166 does not include the output discharge function.

The ADP165/ADP166 are available in seven output voltage options, ranging from 1.2 V to 3.3 V. The ADP165/ADP166 use the EN pin to enable and disable the VOUT pin under normal operating conditions. When EN is high, VOUT turns on, and when EN is low, VOUT turns off. For automatic startup, tie EN to VIN.

Downloaded from Arrow.com.

APPLICATIONS INFORMATION

CAPACITOR SELECTION

Output Capacitor, C_{OUT}

The ADP165/ADP166 are designed for operation with small, space-saving ceramic capacitors, but function with most commonly used capacitors as long as care is taken with regard to the ESR value. The ESR of the output capacitor affects stability of the LDO control loop. A minimum of 1 µF capacitance with an ESR of 1 Ω or less is recommended to ensure stability of the ADP165/ADP166. Transient response to changes in load current is also affected by output capacitance. Using a larger value of output capacitance improves the transient response of the ADP165/ADP166 to large changes in load current. Figure 36 and Figure 37 show the transient responses for output capacitance values of 1 µF and 10 µF, respectively.

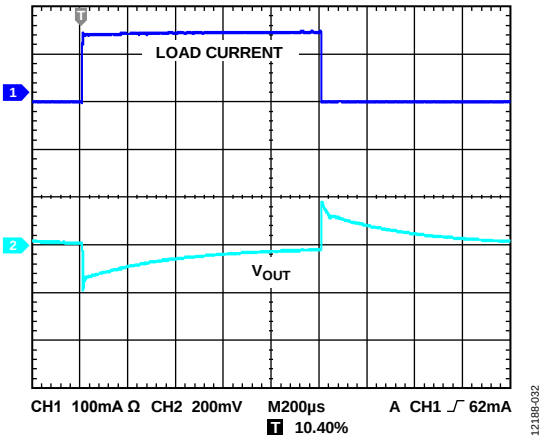


Figure 36. Output Transient Response, C_{OUT} = 1 µF, CH1 = Load Current, CH2 = V_{OUT}

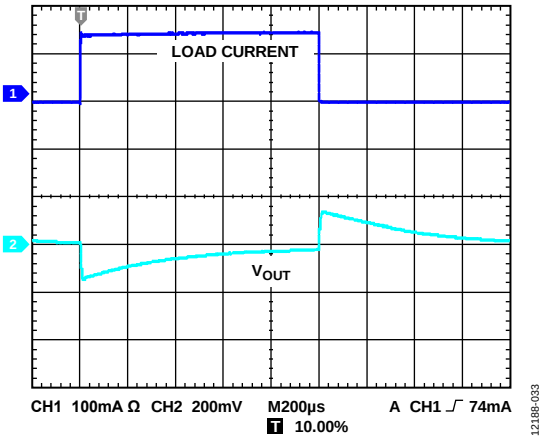


Figure 37. Output Transient Response, C_{OUT} = 10 µF, CH1 = Load Current, CH2 = V_{OUT}

Input Bypass Capacitor, C_{IN}

Connecting a 1 µF capacitor from VIN to GND reduces the circuit sensitivity to the PCB layout, especially when long input traces or high source impedance are encountered. If an output capacitance of greater than 1 µF is required, increase the input capacitor to match it.

Input and Output Capacitor Properties

Any good quality ceramic capacitors can be used with the ADP165/ADP166, as long as they meet the minimum capacitance and maximum ESR requirements. Ceramic capacitors are manufactured with a variety of dielectrics, each with different behavior over temperature and applied voltage. Capacitors must have a dielectric adequate to ensure the minimum capacitance over the necessary temperature range and dc bias conditions. X5R or X7R dielectrics with a voltage rating of 6.3 V or 10 V are recommended. Y5V and Z5U dielectrics are not recommended due to their poor temperature and dc bias characteristics.

Figure 38 depicts the capacitance vs. voltage bias characteristic of a 0402, 1 µF, 10 V, X5R capacitor. The voltage stability of a capacitor is strongly influenced by the capacitor size and voltage rating. In general, a capacitor in a larger package or higher voltage rating exhibits better stability. The temperature variation of the X5R dielectric is about ±15% over the −40°C to +85°C temperature range and is not a function of package or voltage rating.

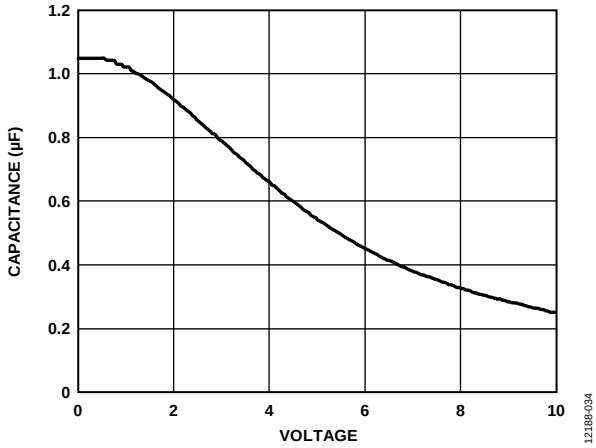


Figure 38. Capacitance vs. Voltage Bias Characteristic

Use Equation 1 to determine the worst-case capacitance accounting for capacitor variation over temperature, component tolerance, and voltage.

$$C_{EFF} = C_{BIAS} \times (1 - TEMPCO) \times (1 - TOL) \quad (1)$$

where:

C_{BIAS} is the effective capacitance at the operating voltage.
TEMPCO is the worst-case capacitor temperature coefficient.
TOL is the worst-case component tolerance.

In this example, the worst-case temperature coefficient (TEMPCO) over the −40°C to +85°C range is 15% for an X5R dielectric. The tolerance of the capacitor (TOL) is 10%, and C_{BIAS} is 0.94 µF at 1.8 V, as shown in Figure 38.

Substituting these values in Equation 1 yields

$$C_{EFF} = 0.94\ \mu F \times (1 - 0.15) \times (1 - 0.1) = 0.719\ \mu F$$

Downloaded from Arrow.com.

Therefore, the capacitor chosen in this example meets the minimum capacitance requirement of the LDO over temperature and tolerance at the chosen output voltage.

To guarantee the performance of the ADP165/ADP166, it is imperative that the effects of dc bias, temperature, and tolerances on the behavior of the capacitors are evaluated for each.

ENABLE FEATURE

The ADP165/ADP166 use the EN pin to enable and disable the VOUT pin under normal operating conditions. As shown in Figure 39, when a rising voltage on EN crosses the active threshold, VOUT turns on. When a falling voltage on EN crosses the inactive threshold, VOUT turns off.

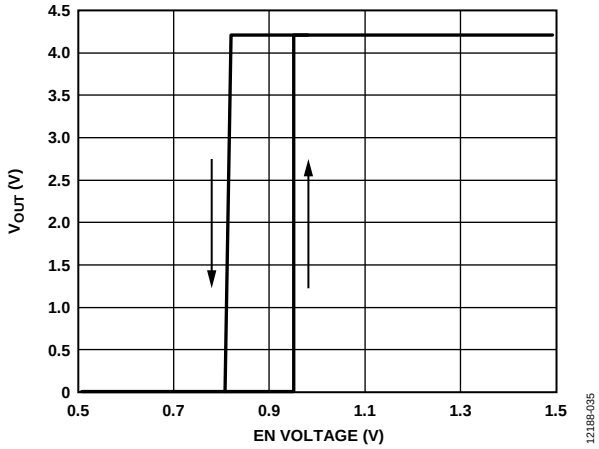


Figure 39. Typical EN Pin Operation

As shown in Figure 39, the EN pin has hysteresis built in, which prevents on/off oscillations that can occur due to noise on the EN pin as it passes through the threshold points.

The EN pin active/inactive thresholds are derived from the VIN voltage. Therefore, these thresholds vary with changing input voltage. Figure 40 shows typical EN active/inactive thresholds when the input voltage varies from 2.2 V to 5.5 V.

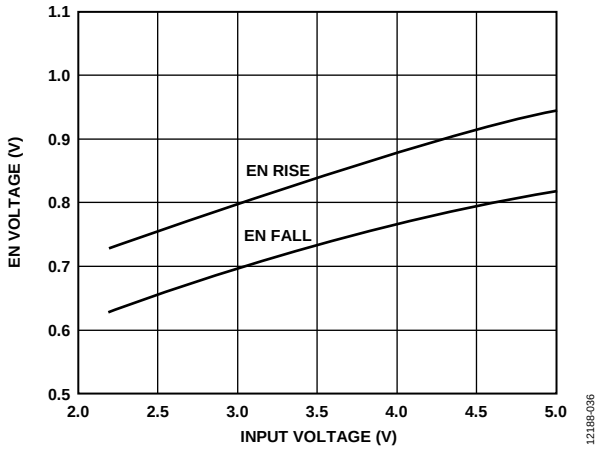


Figure 40. Typical EN Pin Thresholds vs. Input Voltage

The start-up behavior of the ADP165/ADP166 is shown in Figure 41.

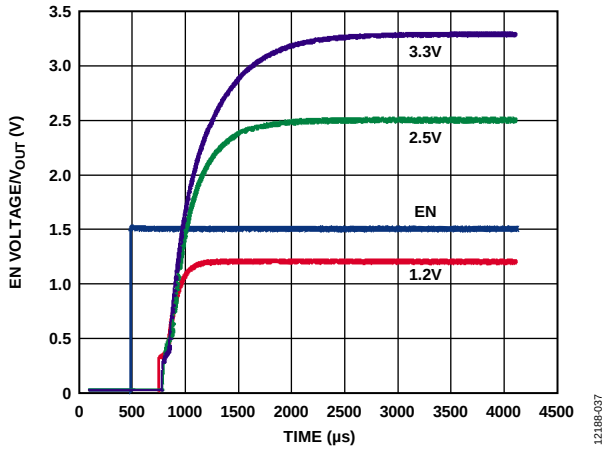


Figure 41. Typical Start-Up Behavior

The shutdown behavior of the ADP165/ADP166 is shown in Figure 42.

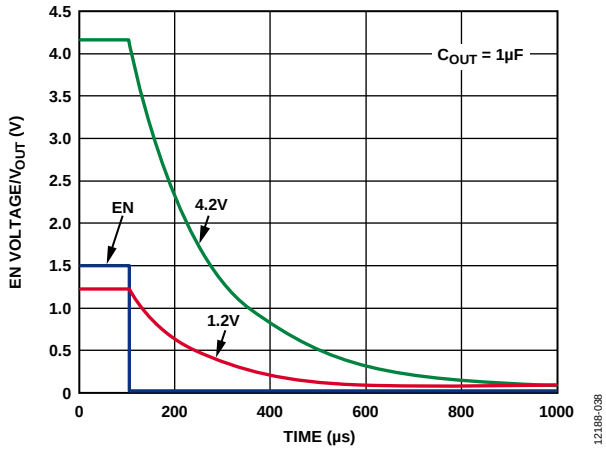


Figure 42. Typical Shutdown Behavior, No Load

UNDERVOLTAGE LOCKOUT (UVLO)

The ADP165/ADP166 also incorporates an internal UVLO circuit to disable the output voltage when the input voltage is less than the minimum input voltage rating of the regulator.

CURRENT-LIMIT AND THERMAL OVERLOAD PROTECTION

The ADP165/ADP166 are protected against damage due to excessive power dissipation by short-circuit and thermal overload protection circuits. The ADP165/ADP166 are designed to limit current when the output load reaches 320 mA (typical). When the output load exceeds 320 mA, the output voltage is reduced to maintain a constant current limit.

Thermal overload protection is included, which limits the junction temperature to a maximum of 150°C (typical). Under extreme conditions (that is, high ambient temperature and power dissipation), when the junction temperature starts to rise above 150°C, the output turns off, reducing the output current to zero. When the junction temperature drops below 135°C, the output turns on again, and the output current is restored to its nominal value.

Downloaded from Arrow.com.

Consider the case where a hard short from VOUT to ground occurs. At first, the ADP165/ADP166 limit current so that only 320 mA is conducted into the short.

If self-heating of the junction temperature is great enough to cause its temperature to rise above 150°C, thermal shutdown activates, turning off the output and reducing the output current to zero. As the junction temperature cools and drops below 135°C, the output turns on and conducts 320 mA into the short, again causing the junction temperature to rise above 150°C. This thermal oscillation between 135°C and 150°C causes a current oscillation between 320 mA and 0 mA that continues as long as the short remains at the output.

Current and thermal limit protections are intended to protect the device against accidental overload conditions. For reliable operation, device power dissipation must be externally limited so that junction temperatures do not exceed 125°C.

THERMAL CONSIDERATIONS

In most applications, the ADP165/ADP166 do not dissipate much heat due to their high efficiency. However, in applications with high ambient temperature and high supply voltage to output voltage differential, the heat dissipated in the package is high enough that it can cause the junction temperature of the die to exceed the maximum junction temperature of 125°C.

When the junction temperature exceeds 150°C, the converter enters thermal shutdown. It recovers only after the junction temperature has decreased below 135°C to prevent any permanent damage. Therefore, thermal analysis for the chosen application is very important to guarantee reliable performance over all conditions. The junction temperature of the die is the sum of the ambient temperature of the environment and the temperature rise of the package due to the power dissipation, as shown in Equation 2.

To guarantee reliable operation, the junction temperature of the ADP165/ADP166 must not exceed 125°C. To ensure that the junction temperature stays below this maximum value, the user must be aware of the parameters that contribute to junction temperature changes. These parameters include ambient temperature, power dissipation in the power device, and thermal resistances between the junction and ambient air (θ_{JA}). The θ_{JA} number is dependent on the package assembly compounds that are used and the amount of copper used to solder the package GND pins to the PCB.

Table 10 shows the typical θ_{JA} values of the 5-lead TSOT, 6-lead LFCSP, and the 4-ball WLCSP for various PCB copper sizes. Table 11 shows the typical Ψ_{JB} value of the 5-lead TSOT, 6-lead LFCSP, and 4-ball WLCSP.

Table 10. Typical θ_{JA} Values

	θ_{JA} (°C/W)		
Copper Size (mm²)	**TSOT**	**LFCSP**	**WLCSP**
0[1]	170	175.1	260
50	152	135.6	159
100	146	77.3	157
300	134	65.2	153
500	131	51	151

[1] Device soldered to minimum size pin traces.

Table 11. Typical Ψ_{JB} Values

Package	Ψ_{JB}	Unit
5-Lead TSOT	42.8	(°C/W)
6-Lead LFCSP	17.9	(°C/W)
4-Ball WLCSP	58.4	(°C/W)

Calculate the junction temperature of the ADP165/ADP166 from the following equation:

$$T_J = T_A + (P_D \times \theta_{JA}) \quad (2)$$

where:
T_A is the ambient temperature.
P_D is the power dissipation in the die, given by

$$P_D = [(V_{IN} - V_{OUT}) \times I_{LOAD}] + (V_{IN} \times I_{GND}) \quad (3)$$

where:
V_{IN} and V_{OUT} are input and output voltages, respectively.
I_{LOAD} is the load current.
I_{GND} is the ground current.

Power dissipation due to ground current is quite small and can be ignored. Therefore, the junction temperature equation simplifies to the following:

$$T_J = T_A + \theta_{JA}[(V_{IN} - V_{OUT}) \times I_{LOAD}] \quad (4)$$

As shown in Equation 4, for a given ambient temperature, input-to-output voltage differential, and continuous load current, there exists a minimum copper size requirement for the PCB to ensure the junction temperature does not rise above 125°C. Figure 43 to Figure 57 show the junction temperature calculations for the different ambient temperatures, load currents, V_{IN}-to-V_{OUT} differentials, and areas of PCB copper.

In the case where the board temperature is known, use the thermal characterization parameter, Ψ_{JB}, to estimate the junction temperature rise (see Figure 55 to Figure 57). Maximum junction temperature (T_J) is calculated from the board temperature (T_B) and power dissipation (P_D) using the following formula:

$$T_J = T_B + (P_D \times \Psi_{JB}) \quad (5)$$

The typical value of Ψ_{JB} is 17.9°C/W for the 6-lead LFCSP package, 42.8°C/W for the 5-lead TSOT package, and 58.4°C/W for the 4-ball WLCSP package.

Downloaded from Arrow.com.

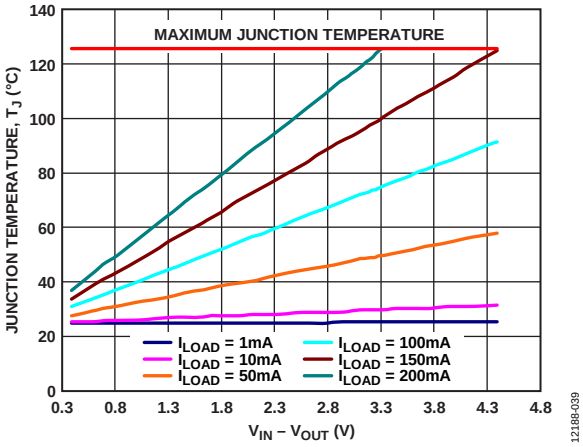


Figure 43. 500 mm² of PCB Copper, WLCSP, T_A = 25°C

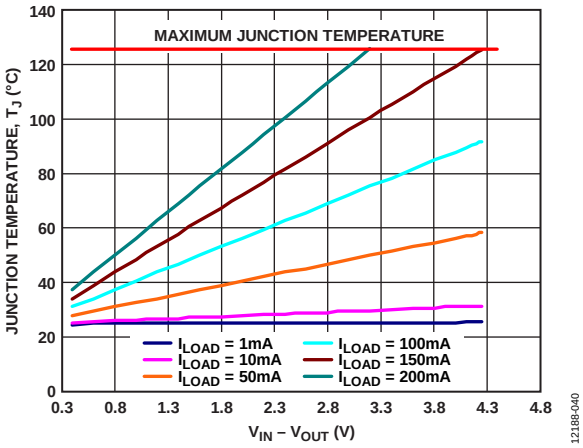


Figure 44. 100 mm² of PCB Copper, WLCSP, T_A = 25°C

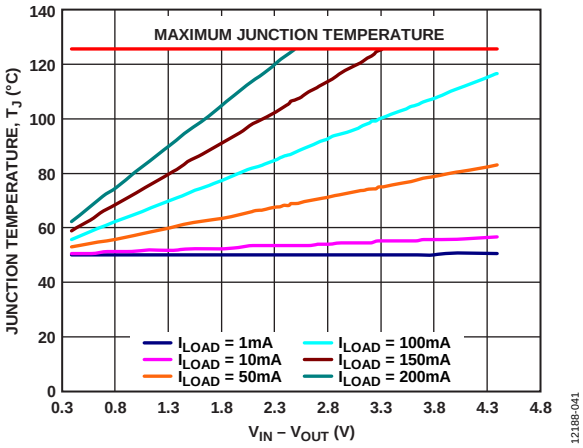


Figure 45. 500 mm² of PCB Copper, WLCSP, T_A = 50°C

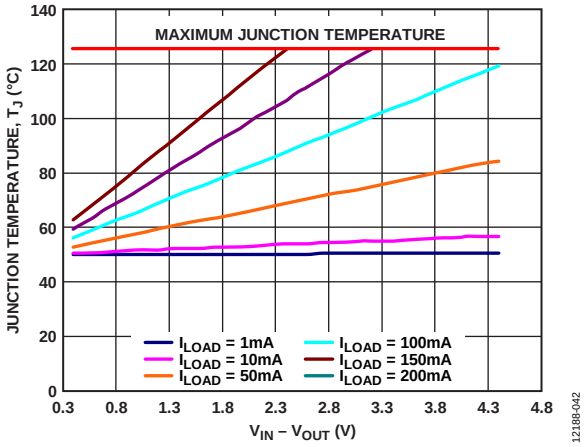


Figure 46. 100 mm² of PCB Copper, WLCSP, T_A = 50°C

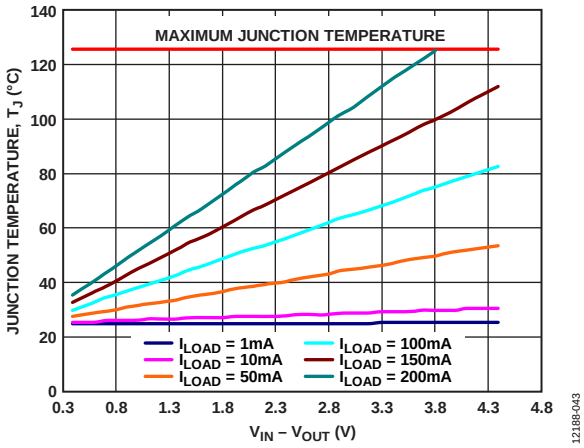


Figure 47. 500 mm² of PCB Copper, TSOT, T_A = 25°C

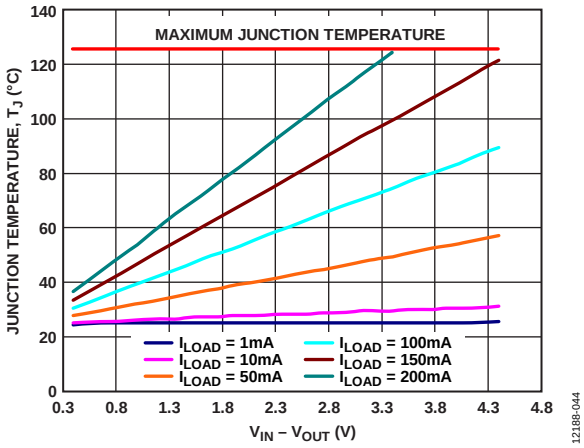


Figure 48. 100 mm² of PCB Copper, TSOT, T_A = 25°C

Downloaded from Arrow.com.

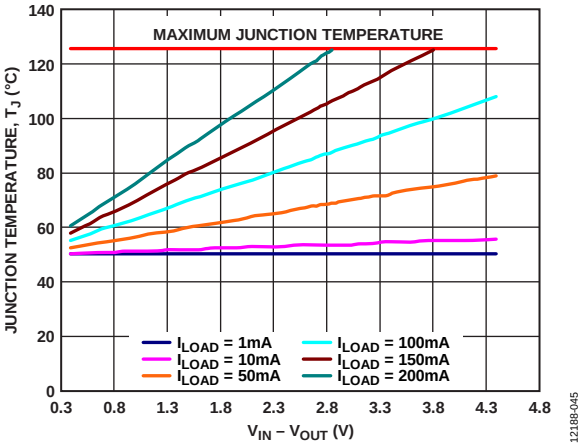


Figure 49. 500 mm² of PCB Copper, TSOT, T_A = 50°C

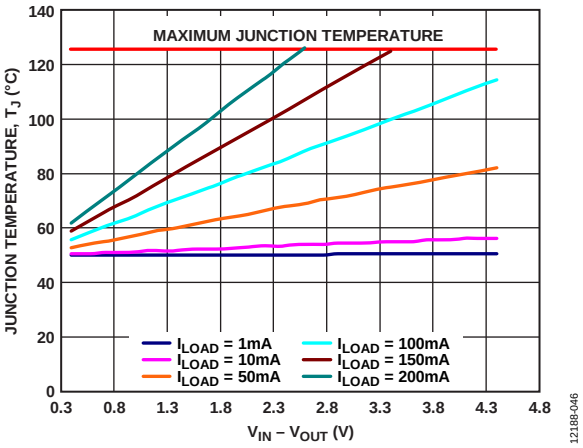


Figure 50. 100 mm² of PCB Copper, TSOT, T_A = 50°C

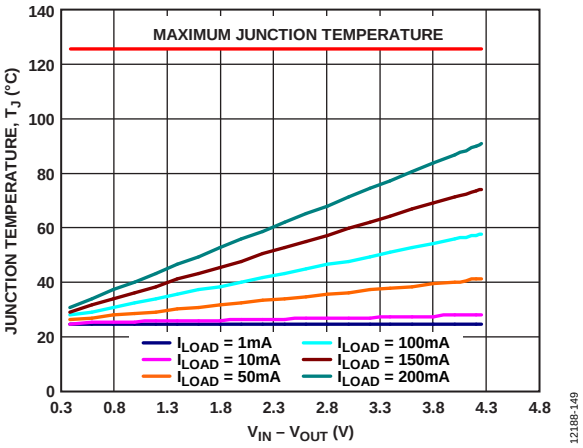


Figure 51. 500 mm² of PCB Copper, LFCSP, T_A = 25°C

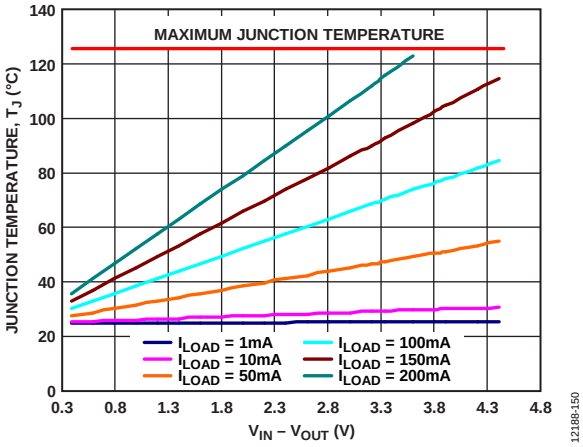


Figure 52. 100 mm² of PCB Copper, LFCSP, T_A = 25°C

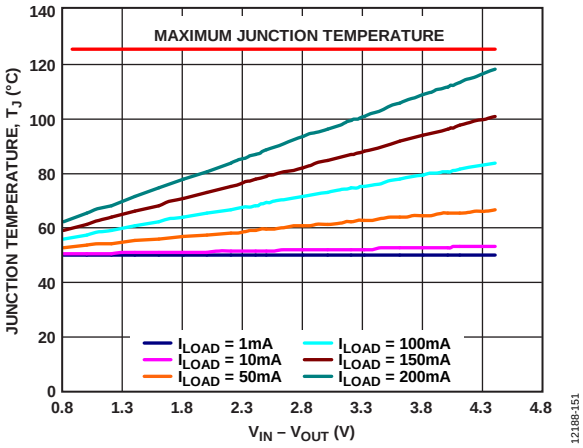


Figure 53. 500 mm² of PCB Copper, LFCSP, T_A = 50°C

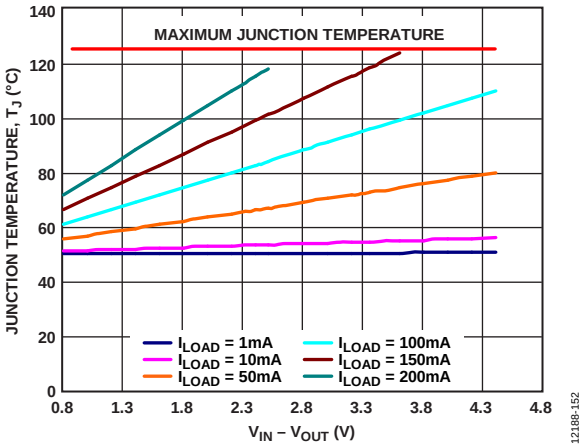


Figure 54. 100 mm² of PCB Copper, LFCSP, T_A = 50°C

Downloaded from Arrow.com.

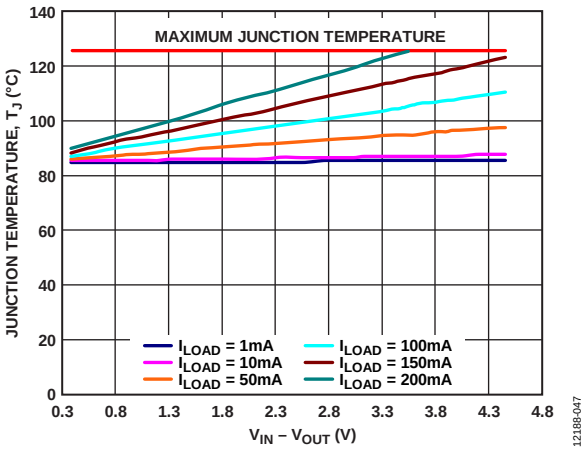


Figure 55. WLCSP, T_A = 85°C

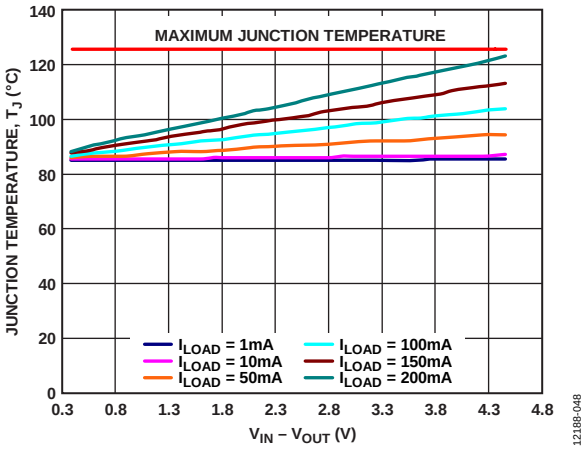


Figure 56. TSOT, T_A = 85°C

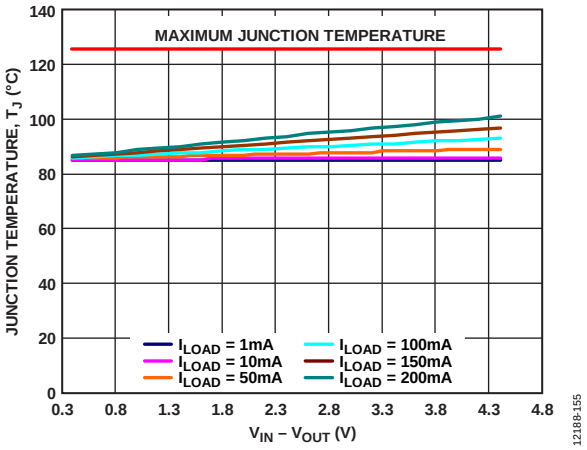


Figure 57. LFCSP, T_A = 85°C

Heat dissipation from the package can be improved by increasing the amount of copper attached to the pins of the ADP165/ADP166. However, as listed in Table 10, a point of diminishing returns is reached eventually, beyond which an increase in the copper size does not yield significant heat dissipation benefits.

PCB LAYOUT CONSIDERATIONS

Place the input capacitor as close as possible to the VIN pin and the GND pin. Place the output capacitor as close as possible to the VOUT pin and the GND pin. Use of 0402 or 0603 size capacitors and resistors achieves the smallest possible footprint solution on boards where area is limited.

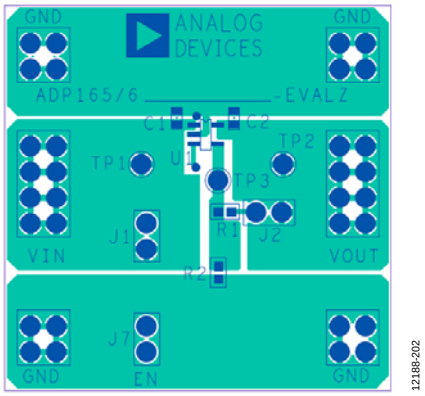


Figure 58. Example of 5-Lead TSOT PCB Layout

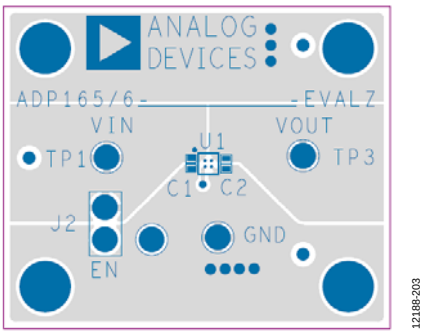


Figure 59. Example of 4-Ball WLCSP PCB Layout

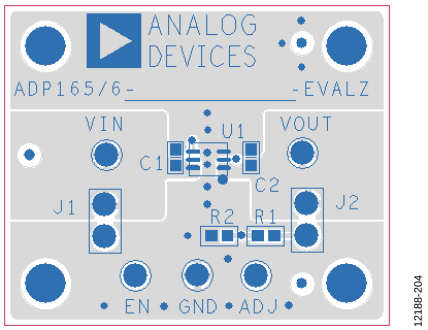


Figure 60. Example of 6-Lead LFCSP PCB Layout

Downloaded from Arrow.com.

LIGHT SENSITIVITY OF WLCSPs

The WLCSP package option is essentially a silicon die with additional post fabrication dielectric and metal processing designed to contact solder bumps on the active side of the chip. With this package type, the die is exposed to ambient light and is subject to photoelectric effects. Light sensitivity analysis of a WLCSP mounted on standard PCB material reveals that performance may be impacted when the package is illuminated directly by high intensity light. No degradation in electrical performance is observed due to illumination by low intensity (0.1 mW/cm^2) ambient light. Direct sunlight can have intensities of 50 mW/cm^2, and office ambient light can be as low as 0.1 mW/cm^2.

When the WLCSP is assembled on the board with the bump side of the die facing the PCB, reflected light from the PCB surface is incident on active silicon circuit areas and results in the increased leakage currents. No performance degradation occurs due to illumination of the backside (substrate) of the WLCSP.

All WLCSPs are particularly sensitive to incident light with wavelengths in the near infrared range (NIR, 700 nm to 1000 nm). Photons in this waveband have a longer wavelength and lower energy than photons in the visible (400 nm to 700 nm) and near ultraviolet (NUV, 200 nm to 400 nm) bands; therefore, they can penetrate more deeply into the active silicon.

Incident light with wavelengths greater than 1100 nm has no photoelectric effect on silicon devices because silicon is transparent to wavelengths in this range.

The spectral content of conventional light sources varies considerably. Sunlight has a broad spectral range, with peak intensity in the visible band that falls off in the NUV and NIR bands; fluorescent lamps have significant peaks in the visible but not the NUV or NIR bands. Tungsten lighting has a broad peak in the longer visible wavelengths with a significant tail in the NIR.

Efforts have been made at a product level to reduce the effect of ambient light; the under bump metal (UBM) has been designed to shield the sensitive circuit areas on the active side (bump side) of the die. However, if an application encounters any light sensitivity with the WLCSP, shielding the bump side of the WLCSP package with opaque material eliminates this effect. Shielding can be accomplished using materials such as silica-filled liquid epoxies like those used in flip-chip underfill techniques.

Downloaded from Arrow.com.

OUTLINE DIMENSIONS

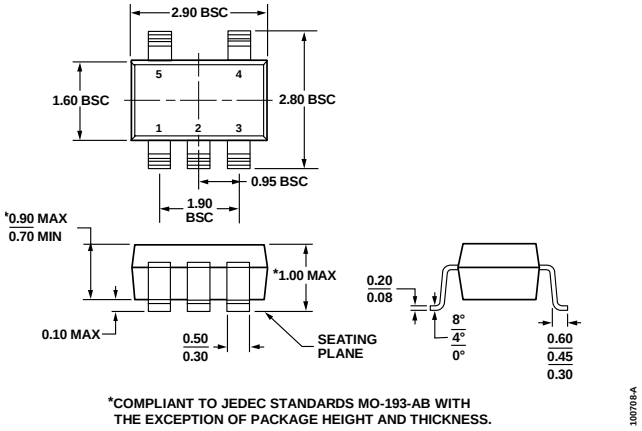


Figure 61. 5-Lead Thin Small Outline Transistor Package [TSOT] (UJ-5)
Dimensions shown in millimeters

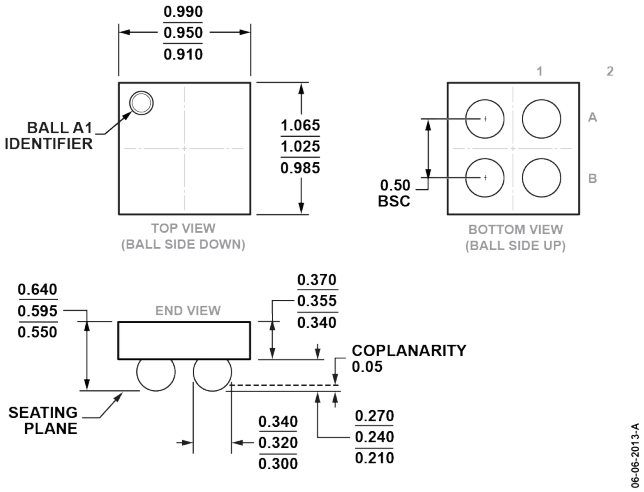


Figure 62. 4-Ball Wafer Level Chip Scale Package [WLCSP] (CB-4-4)
Dimensions shown in millimeters

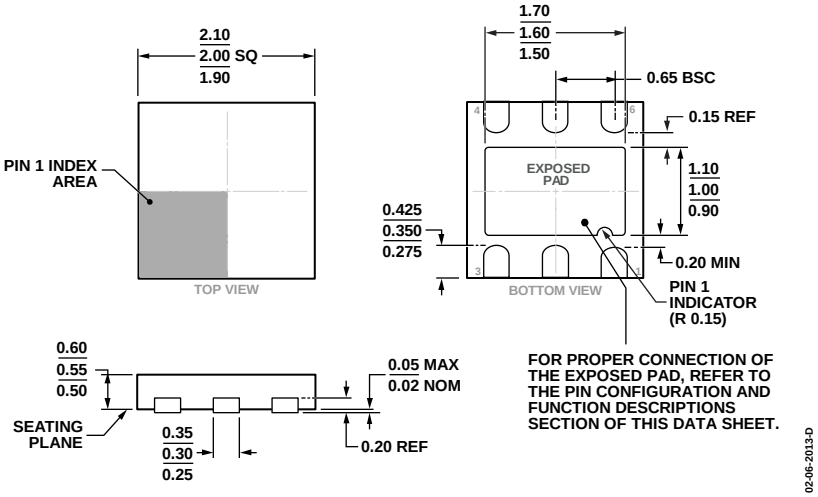


Figure 63. 6-Lead Lead Frame Chip Scale Package [LFCSP_UD] 2.00 mm × 2.00 mm Body, Ultra Thin, Dual Lead (CP-6-3)
Dimensions show in millimeters

Downloaded from Arrow.com.

ORDERING GUIDE

Model[1]	Temperature Range	Output Voltage (V)	Package Description	Package Option	Branding
ADP165ACBZ-1.2-R7	−40°C to +125°C	1.2	4-Ball Wafer Level Chip Scale Package [WLCSP]	CB-4-4	CX
ADP165ACBZ-1.8-R7	−40°C to +125°C	1.8	4-Ball Wafer Level Chip Scale Package [WLCSP]	CB-4-4	CY
ADP165ACBZ-2.2-R7	−40°C to +125°C	2.2	4-Ball Wafer Level Chip Scale Package [WLCSP]	CB-4-4	CZ
ADP165ACBZ-2.3-R7	−40°C to +125°C	2.3	4-Ball Wafer Level Chip Scale Package [WLCSP]	CB-4-4	D4
ADP165ACBZ-2.85-R7	−40°C to +125°C	2.85	4-Ball Wafer Level Chip Scale Package [WLCSP]	CB-4-4	D7
ADP165ACBZ-3.0-R7	−40°C to +125°C	3.0	4-Ball Wafer Level Chip Scale Package [WLCSP]	CB-4-4	D5
ADP165ACBZ-3.3-R7	−40°C to +125°C	3.3	4-Ball Wafer Level Chip Scale Package [WLCSP]	CB-4-4	D6
ADP165ACPZN-1.2-R7	−40°C to +125°C	1.2	6-Lead Lead Frame Chip Scale Package [LFCSP_UD]	CP-6-3	LQL
ADP165ACPZN-1.8-R7	−40°C to +125°C	1.8	6-Lead Lead Frame Chip Scale Package [LFCSP_UD]	CP-6-3	LQM
ADP165ACPZN-2.3-R7	−40°C to +125°C	2.3	6-Lead Lead Frame Chip Scale Package [LFCSP_UD]	CP-6-3	LQN
ADP165ACPZN-3.0-R7	−40°C to +125°C	3.0	6-Lead Lead Frame Chip Scale Package [LFCSP_UD]	CP-6-3	LQP
ADP165ACPZN-3.3-R7	−40°C to +125°C	3.3	6-Lead Lead Frame Chip Scale Package [LFCSP_UD]	CP-6-3	LQQ
ADP165ACPZN-R7	−40°C to +125°C	Adjustable	6-Lead Lead Frame Chip Scale Package [LFCSP_UD]	CP-6-3	LQR
ADP165AUJZ-1.2-R7	−40°C to +125°C	1.2	5-Lead Thin Small Outline Transition [TSOT]	UJ-5	LQL
ADP165AUJZ-1.8-R7	−40°C to +125°C	1.8	5-Lead Thin Small Outline Transition [TSOT]	UJ-5	LQM
ADP165AUJZ-2.3-R7	−40°C to +125°C	2.3	5-Lead Thin Small Outline Transition [TSOT]	UJ-5	LQN
ADP165AUJZ-3.0-R7	−40°C to +125°C	3.0	5-Lead Thin Small Outline Transition [TSOT]	UJ-5	LQP
ADP165AUJZ-3.3-R7	−40°C to +125°C	3.3	5-Lead Thin Small Outline Transition [TSOT]	UJ-5	LQQ
ADP165AUJZ-R7	−40°C to +125°C	Adjustable	5-Lead Thin Small Outline Transition [TSOT]	UJ-5	LQR
ADP166ACBZ-1.2-R7	−40°C to +125°C	1.2	4-Ball Wafer Level Chip Scale Package [WLCSP]	CB-4-4	D9
ADP166ACBZ-1.8-R7	−40°C to +125°C	1.8	4-Ball Wafer Level Chip Scale Package [WLCSP]	CB-4-4	DA
ADP166ACBZ-2.2-R7	−40°C to +125°C	2.2	4-Ball Wafer Level Chip Scale Package [WLCSP]	CB-4-4	DB
ADP166ACBZ-2.3-R7	−40°C to +125°C	2.3	4-Ball Wafer Level Chip Scale Package [WLCSP]	CB-4-4	DC
ADP166ACBZ-2.85-R7	−40°C to +125°C	2.85	4-Ball Wafer Level Chip Scale Package [WLCSP]	CB-4-4	DD
ADP166ACBZ-3.0-R7	−40°C to +125°C	3.0	4-Ball Wafer Level Chip Scale Package [WLCSP]	CB-4-4	DE
ADP166ACBZ-3.3-R7	−40°C to +125°C	3.3	4-Ball Wafer Level Chip Scale Package [WLCSP]	CB-4-4	DF
ADP166ACPZN-1.2-R7	−40°C to +125°C	1.2	6-Lead Lead Frame Chip Scale Package [LFCSP_UD]	CP-6-3	LR6
ADP166ACPZN-1.8-R7	−40°C to +125°C	1.8	6-Lead Lead Frame Chip Scale Package [LFCSP_UD]	CP-6-3	LR7
ADP166ACPZN-2.3-R7	−40°C to +125°C	2.3	6-Lead Lead Frame Chip Scale Package [LFCSP_UD]	CP-6-3	LR8
ADP166ACPZN-3.0-R7	−40°C to +125°C	3.0	6-Lead Lead Frame Chip Scale Package [LFCSP_UD]	CP-6-3	LR9
ADP166ACPZN-3.3-R7	−40°C to +125°C	3.3	6-Lead Lead Frame Chip Scale Package [LFCSP_UD]	CP-6-3	LRA
ADP166ACPZN-R7	−40°C to +125°C	Adjustable	6-Lead Lead Frame Chip Scale Package [LFCSP_UD]	CP-6-3	LR5
ADP166AUJZ-1.2-R7	−40°C to +125°C	1.2	5-Lead Thin Small Outline Transition [TSOT]	UJ-5	LR6
ADP166AUJZ-1.8-R7	−40°C to +125°C	1.8	5-Lead Thin Small Outline Transition [TSOT]	UJ-5	LR7
ADP166AUJZ-2.3-R7	−40°C to +125°C	2.3	5-Lead Thin Small Outline Transition [TSOT]	UJ-5	LR8
ADP166AUJZ-3.0-R7	−40°C to +125°C	3.0	5-Lead Thin Small Outline Transition [TSOT]	UJ-5	LR9
ADP166AUJZ-3.3-R7	−40°C to +125°C	3.3	5-Lead Thin Small Outline Transition [TSOT]	UJ-5	LRA
ADP166AUJZ-R7	−40°C to +125°C	Adjustable	5-Lead Thin Small Outline Transition [TSOT]	UJ-5	LR5
ADP165Z-REDYKIT			Evaluation Board		
ADP166Z-REDYKIT			Evaluation Board		

[1] Z = RoHS Compliant Part.

©2026 Analog Devices, Inc. All rights reserved. Trademarks and registered trademarks are the property of their respective owners.
D12188-0-7/26(C)

Downloaded from Arrow.com.